NPN Epitaxial Planar Silicon Transistor

2SC3070



# High h<sub>FE</sub>, Low-Frequency General-Purpose Amplifier Applications

## Applications

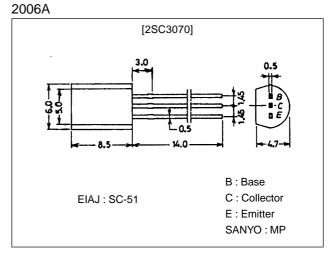
· Low-frequency, general-purpose amplifier., various drivers, muting circuit.

### www.DataShee Features

- · High DC current gain ( $h_{FE}$ =800 to 3200).
- · Large current capacity ( $I_C=1.2A$ ).
- $\cdot$  Low collector-to-emitter saturation voltage
- $(V_{CE(sat)}=0.5V \text{ max}).$
- $\cdot$  High V<sub>EBO</sub> (V<sub>EBO</sub> $\geq$ 15V).

## **Package Dimensions**

unit:mm



## **Specifications**

#### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		30	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		25	V
Emitter-to-Base Voltage	VEBO		15	V
Collector Current	IC		1.2	А
Collector Current (Pulse)	ICP		2	A
Base Current	Ι <sub>Β</sub>		240	mA
Collector Dissipation	PC		1	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

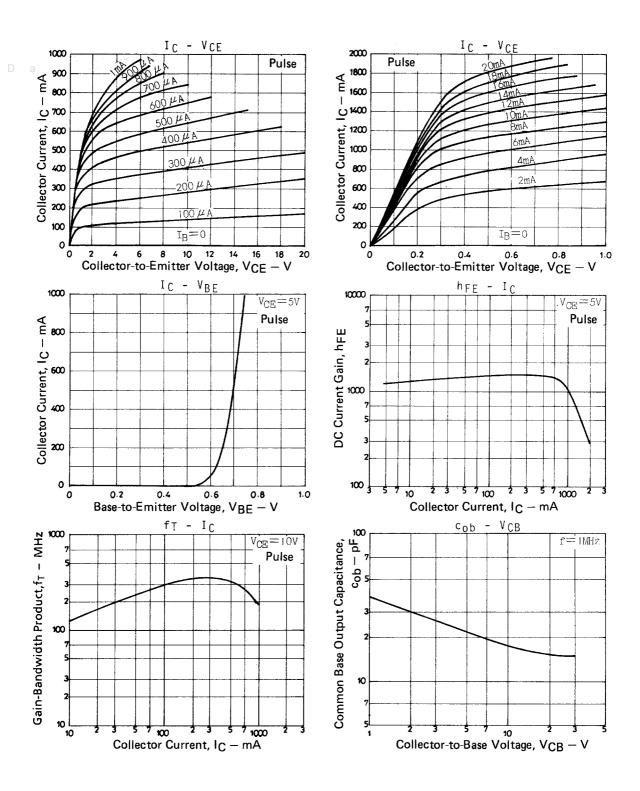
#### **Electrical Characteristics at Ta = 25°C**

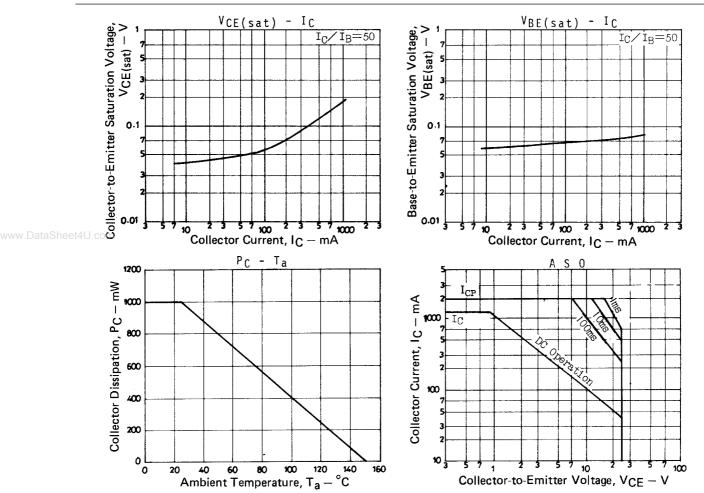
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Collector Cutoff Current	ICBO	V <sub>CB</sub> =20V, I <sub>E</sub> =0			0.1	μΑ
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =10V, I <sub>C</sub> =0			0.1	μA
DC Current Gain	hFE1	V <sub>CE</sub> =5V, I <sub>C</sub> =500mA	800	1500	3200	
	h <sub>FE</sub> 2	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA	600			
Gain-Bandwidth Product	fT	V <sub>CE</sub> =10V, I <sub>C</sub> =50mA		220		MHz
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		17		pF

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =500mA, I <sub>B</sub> =10mA		0.12	0.5	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =10mA		0.85	1.2	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =10μA, I <sub>E</sub> =0	30			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =1mA, R <sub>BE</sub> =∞	25			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	Ι <sub>Ε</sub> =10μΑ, Ι <sub>C</sub> =0	15			V





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